

TL331, TL331V

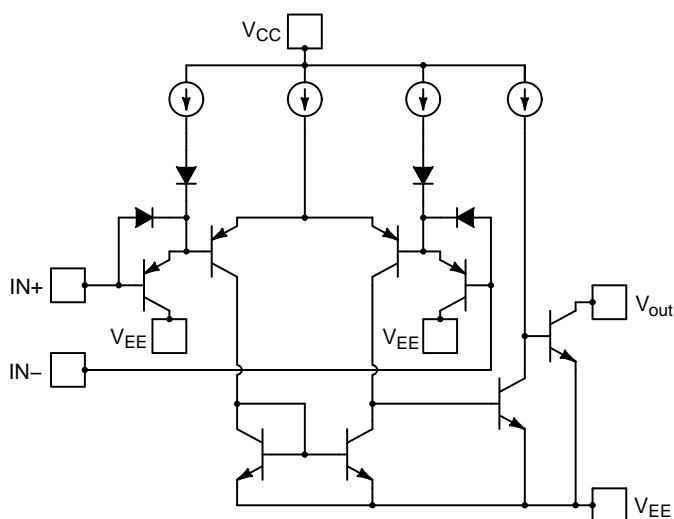
Comparator, Single Channel, Open Collector, Low Power, Wide Supply Range

Description

The TL331 is an open collector, low-power comparator designed specifically to operate over a wide supply range from 2 V to 36 V single supply and ± 1 V to ± 18 V for split supplies. The input common-mode voltage range includes ground, even when operated from a single power supply voltage. TL331 comes in a space saving TSOP-5 package and is also available in an automotive qualified version.

Features

- Wide Single Supply Voltage Range or Dual Supplies
- Low Supply Current: 0.5 mA Typical
- Low Input Bias Current: 25 nA Typical
- Low Input Offset Current: ± 5 nA Typical
- Low Input Offset Voltage: ± 2 mV Typical
- Input Common Mode Voltage Range includes Ground
- Low Output Saturation Voltage: 150 mV Typ at $I_O = 4$ mA
- Differential Input Voltage Range Equal to the Supply Voltage
- TTL, DTL, ECL, CMOS Compatible Devices
- TL331V for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable*
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



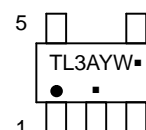
ON Semiconductor®

www.onsemi.com



TSOP-5
SN SUFFIX
CASE 483

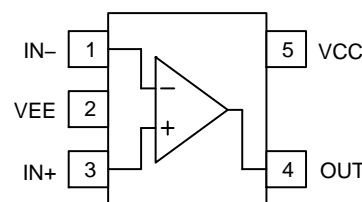
MARKING DIAGRAM



TL3 = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



ORDERING INFORMATION

Device	Package	Shipping†
TL331SN4T3G	TSOP-5 (Pb-Free)	3000 / Tape & Reel
TL331VSN4T3G*	TSOP-5 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

TL331, TL331V

Table 1. MAXIMUM RATINGS (Over operating free-air temperature, unless otherwise stated)

Parameter	Symbol	Limit	Unit
Supply Voltage ($V_{CC} - V_{EE}$)	V_S	36	V

INPUT AND OUTPUT PINS

Input Voltage (Note 1)	V_{IN}	± 36	V
Differential Input Voltage (Note 1)	V_{ID}	-0.3 to 36	V
Output Short Circuit Current (Note 2)	I_{SC}	20	mA

TEMPERATURE

Storage Temperature	T_{STG}	-65 to +150	°C
Junction Temperature	T_J	+150	°C

ESD RATINGS

Human Body Model	HBM	2000	V
Charged Device Model	CDM	2500	V
Machine Model	MM	150	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Positive excursions of the input voltage may exceed the power supply level. The low input voltage state must not be less than 0.3 V below the negative supply rail.
2. Short circuits from the output to V_{CC} can cause excessive heating and potential destruction. The maximum short circuit current is independent of the magnitude of V_{CC} .

Table 2. THERMAL INFORMATION (Note 3)

Parameter	Symbol	Single Layer Board (Note 4)	Multi-Layer Board (Note 5)	Unit
Junction to Ambient Thermal Resistance	θ_{JA}	274	209	°C/W

3. Short-circuits can cause excessive heating and destructive dissipation. These values are typical.
4. Values based on a 1S standard PCB according to JEDEC 51-3 with 1.0 oz copper and a 400 mm² copper area
5. Values based on a 1S2P standard PCB according to JEDEC 51-7 with 1.0 oz copper and a 25 mm² copper area

Table 3. OPERATING CONDITIONS

Parameter	Symbol	Limit	Unit
Operating Supply Voltage	V_S	2 to 36	V
Specified Operating Range	T_A	-40 to +125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

TL331, TL331V

Table 4. ELECTRICAL CHARACTERISTICS (Vs=+5.0 V, At TA = +25°C, VCM = mid-supply, unless otherwise noted)

Boldface limits apply over the specified temperature range, TA = -40°C to +125°C.

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
-----------	--------	-----------------	-----	-----	-----	------

INPUT CHARACTERISTICS

Input Offset Voltage	V _{OS}	V _O = 1.4 V, R _S = 0 Ω, V _S = 5 V to 30 V	V _{CM} = 0 to V _{CC} -1.5 V		1	5	mV
			V _{CM} = 0 to V _{CC} -2 V			9	mV
Input Bias Current	I _{IB}				-25	-250	nA
						-400	nA
Input Offset Current	I _{OS}				5	50	nA
						150	nA
Input Common Mode Range (Note 6)	V _{ICMR}		0			V _{CC} - 1.5	V
Differential Input Voltage (Note 7)	V _{ID}					V _{CC}	V

OUTPUT CHARACTERISTICS

Output Voltage Low	V _{OL}	V _{ID} = -1 V, I _O = 4 mA		150	400	mV
					700	mV
Output Sink Current	I _O	V _{ID} = -1 V, V _O = 1.5 V	6	16		mA
Output Leakage Current	I _{OH}	V _{ID} = 1 V, V _{CC} = V _O = 5 V		0.1	50	nA
		V _{ID} = 1 V, V _{CC} = V _O = 30 V			1	μA

DYNAMIC PERFORMANCE

Large Signal Differential Voltage Gain	A _{VD}	V _{CC} = 15 V, R _{PU} = 15 kΩ, V _O = 1.4 V to 11.4 V	50	200		V/mV
Propagation Delay L-H (Note 8)	t _{PLH}	5 mV overdrive, R _{PU} = 5.1 kΩ		850		ns
		20 mV overdrive, R _{PU} = 5.1 kΩ		600		ns
		100 mV overdrive, R _{PU} = 5.1 kΩ		400		ns
		TTL Input, V _{ref} = +1.4 V, R _{PU} = 5.1 kΩ		300		ns
Propagation Delay H-L	t _{PHL}	5 mV overdrive, R _{PU} = 5.1 kΩ		700		ns
		20 mV overdrive, R _{PU} = 5.1 kΩ		400		ns
		100 mV overdrive, R _{PU} = 5.1 kΩ		250		ns
		TTL Input, V _{ref} = +1.4 V, R _{PU} = 5.1 kΩ		300		ns

POWER SUPPLY

Quiescent Current	I _{CC}	No load, V _{CC} = 5 V		0.5	0.7	mA
		No load, V _{CC} = 30 V		0.6	1.25	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- The input common mode voltage of either input signal should not be allowed to go negative by more than 0.3 V. The upper end of the common mode voltage range is V_{CC} - 1.5 V, but either or both inputs can go to +36 V without damage.
- Positive excursions of the input voltage may exceed the power supply level. As long as the other voltage remains within the common mode range, the comparator will provide a proper output stage. The low input voltage state must not be less than 0.3 V below the negative supply rail.
- TL331 is an open collector comparator. Rise time is a function of the RC time constant. A 5.1 kΩ pull-up resistor was used for these measurements.

TYPICAL CHARACTERISTICS

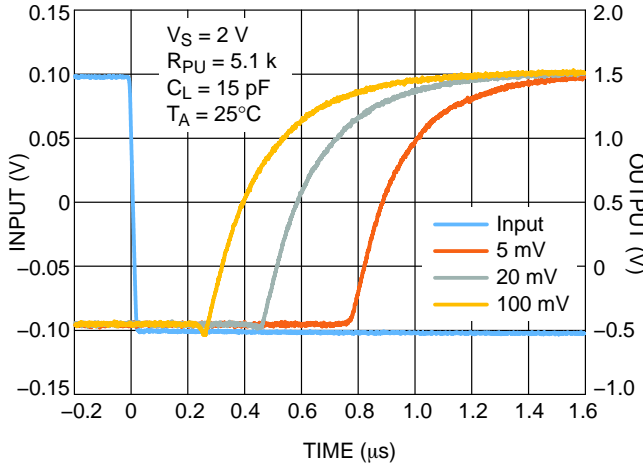


Figure 1. Low-to-High Propagation Delay vs. Overdrive at 2 V Supply

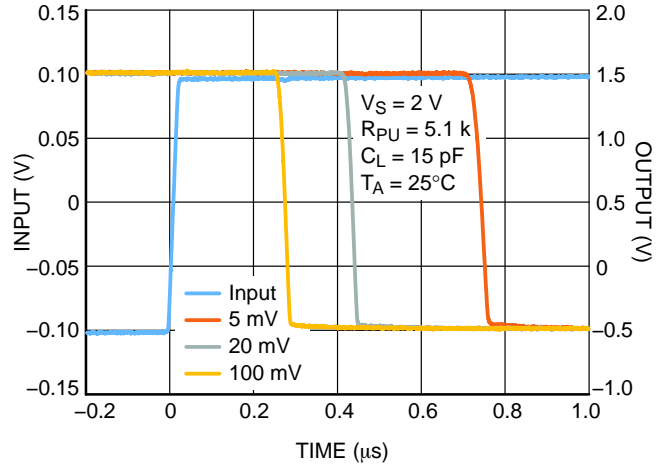


Figure 2. High-to-Low Propagation Delay vs. Overdrive at 2 V Supply

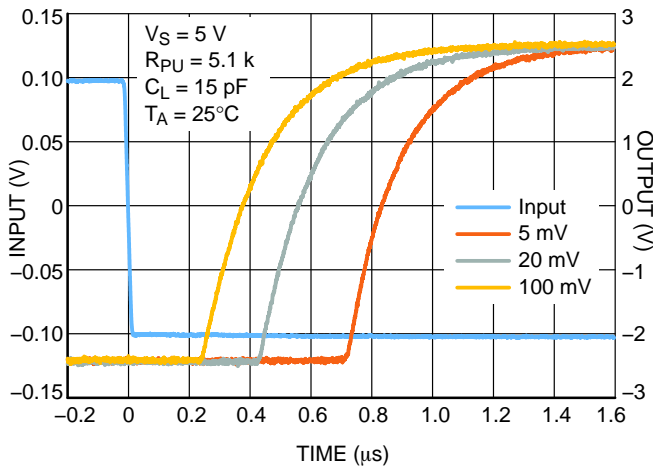


Figure 3. Low-to-High Propagation Delay vs. Overdrive at 5 V Supply

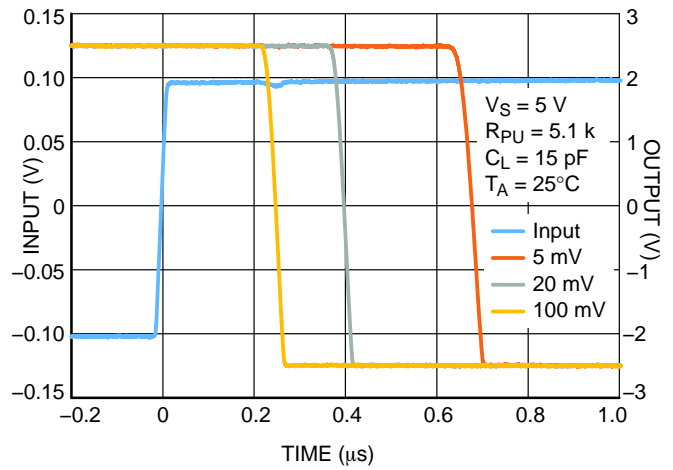


Figure 4. High-to-Low Propagation Delay vs. Overdrive at 5 V Supply

TYPICAL CHARACTERISTICS

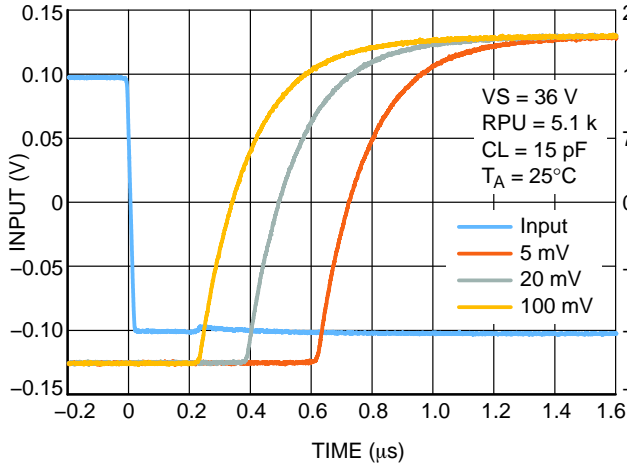


Figure 5. Low-to-High Propagation Delay vs. Overdrive at 36 V Supply

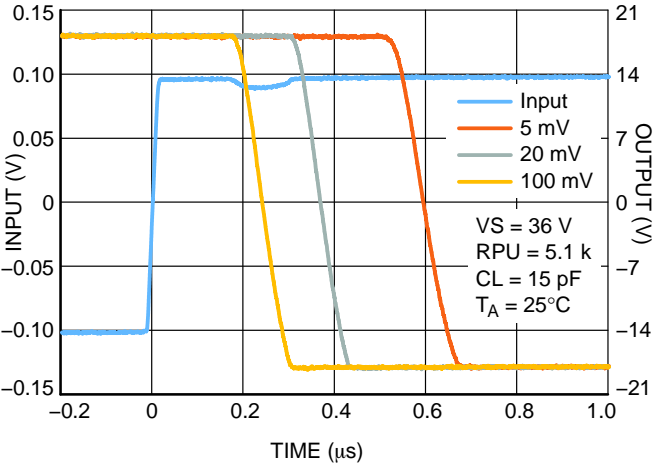


Figure 6. High-to-Low Propagation Delay vs. Overdrive at 36 V Supply

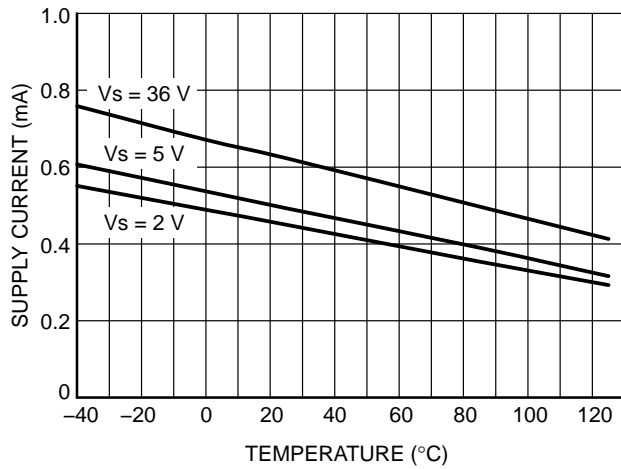


Figure 7. Quiescent Current vs. Temperature

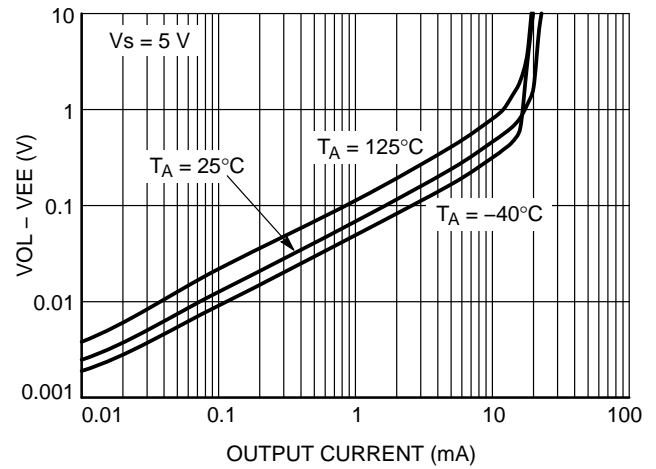
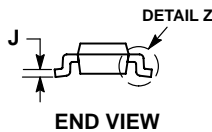
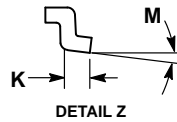
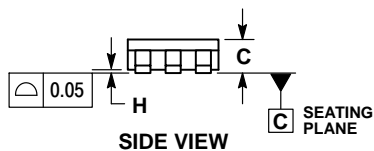
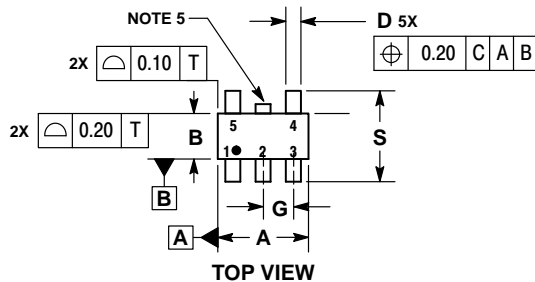


Figure 8. Low Level Output Voltage vs. Output Current at 5 V Supply

TL331, TL331V

PACKAGE DIMENSIONS

TSOP-5 CASE 483 ISSUE M

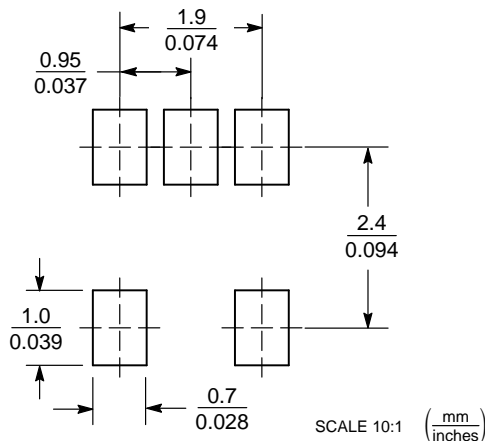


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

DIM	MILLIMETERS	
	MIN	MAX
A	2.85	3.15
B	1.35	1.65
C	0.90	1.10
D	0.25	0.50
G	0.95 BSC	
H	0.01	0.10
J	0.10	0.26
K	0.20	0.60
M	0°	10°
S	2.50	3.00

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marketing.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local Sales Representative

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9